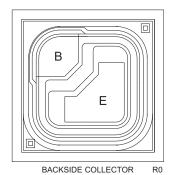


CP788X-2N5087

PNP - General Purpose Transistor Die

The CP788X-2N5087 is a silicon PNP transistor designed for general purpose applications.



MECHANICAL SPECIFICATIONS:

Die Size	13.7 x 13.7 MILS	
Die Thickness	5.9 MILS	
Base Bonding Pad Size	4.0 x 4.0 MILS	
Emitter Bonding Pad Size	5.5 x 5.5 MILS	
Top Side Metalization	Al-Si – 17,000Å	
Back Side Metalization	Au – 9,000Å	
Scribe Alley Width	1.8 MILS	
Wafer Diameter	5 INCHES	
Gross Die Per Wafer	91,469	

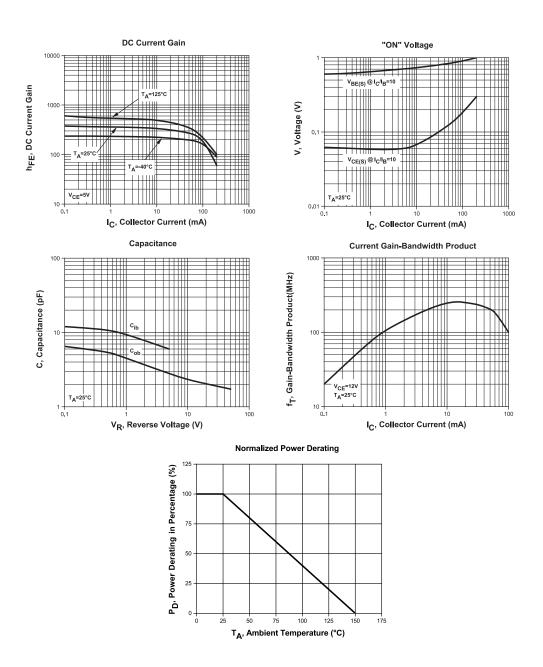
MAXIMUM F	RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Bas	se Voltage	V_{CBO}	50	V
Collector-Emitter Voltage		V_{CEO}	50	V
Emitter-Base Voltage		V_{EBO}	3.0	V
Continuous Collector Current		I _C	50	mA
Operating and Storage Junction Temperature		T_{J},T_{stg}	-65 to +150	°C
SYMBOL	IL CHARACTERISTICS: (T _A =25°C) TEST CONDITIONS V _{CB} =35V	MIN	MAX 50	UNITS nA
ICBO	OB		50	
I _{EBO}	V _{EB} =3.0V		50	nA
BV _{CBO}	I _C =100μA	50		V
BVCEO	I _C =1.0mA	50		V
V _{CE(SAT)}	I _C =10mA, I _B =1.0mA		0.30	V
V _{BE(ON)}	V_{CE} =5.0V, I_{C} =1.0mA		0.85	V
h _{FE})	V_{CE} =5.0V, I_{C} =100 μ A	250	800	
h _{FE}	V_{CE} =5.0V, I_{C} =1.0mA	250		
h _{FE}	V_{CE} =5.0V, I_{C} =10mA	250		
f _T	V_{CE} =5.0V, I_{C} =500 μ A, f=20MHz	40		MHz
C _{ob}	V_{CB} =5.0V, I_{E} =0, f=100kHz		4.0	pF

CP788X-2N5087

Typical Electrical Characteristics

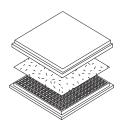


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BARE DIE PACKING OPTIONS

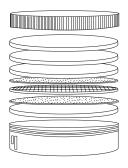




BARE DIE IN TRAY (WAFFLE) PACK

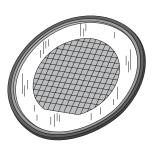
CT: Singulated die in tray (waffle) pack. (example: CP211-PART NUMBER-CT)

CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes). (example: CP211-PART NUMBER-CM)



UNSAWN WAFER

WN: Full wafer, unsawn, 100% tested with reject die inked. (example: CP211-PART NUMBER-WN)



SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring,

100% tested with reject die inked. (example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



Visit the Central website for a complete listing of specifications: www.centralsemi.com/bdspecs

R2 (3-April 2017)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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